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February 2013

# FSFR-HS Series — Advanced Fairchild Power Switch (FPS<sup>™</sup>) for Half-Bridge Resonant Converters

## Features

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- Variable Frequency Control with 50% Duty Cycle for Half-Bridge Resonant Converter Topology
- High Efficiency through Zero Voltage Switching (ZVS)
- Built-in High-Side Gate Driver IC
- Internal UniFET™s with Fast-Recovery Type Body Diode (t<sub>rr</sub>=160 ns Typical)
- Fixed Dead Time (350 ns) Optimized for MOSFETs
- Operating Frequency Up to 600 kHz for Soft-Start
- Self Auto-Restart Operation for All Protections, Despite External LV<sub>CC</sub> Bias
- Line UVLO with Programmable Hysteresis Level
- Simple On/Off with Line UVLO Pin
- Easy Configuration and Compatibility with FAN7930 for Line UVLO without External Components
- Protection Functions: Over-Voltage Protection (OVP), Over-Current Protection (OCP), Abnormal Over-Current Protection (AOCP), Internal Thermal Shutdown (TSD)

## Applications

- PDP and LCD TVs
- Desktop PCs and Servers
- Adapters
- Telecom Power Supplies

Ordering Information

## Description

The FSFR-HS is a highly integrated power switch designed for high-efficiency half-bridge resonant converters. Offering everything necessary to build a reliable and robust resonant converter, the FSFR-HS simplifies designs while improving productivity and performance. The FSFR-HS combines power MOSFETs, a high-side gate-drive circuit, an accurate current-controlled oscillator, and built-in protection functions.

The high-side gate-drive circuit has a common-mode noise cancellation capability, which provides stable operation with excellent noise immunity. Using zerovoltage-switching (ZVS) technique dramatically reduces the switching losses and significantly improves efficiency. The ZVS also reduces the switching noise noticeably, even though the operating frequency increases. It allows a small Electromagnetic Interference (EMI) filter, besides the high operating frequency, to reduce the volume of the resonant tank and to increase power density.

The FSFR-HS can be applied to resonant converter topologies such as series resonant, parallel resonant, and LLC resonant converters.

## **Related Resources**

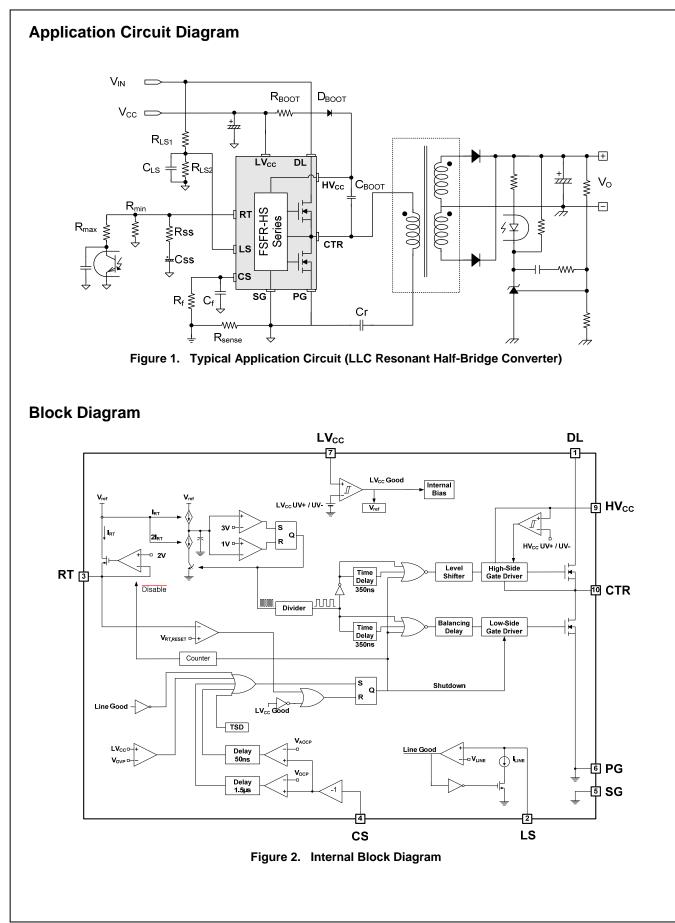
<u>AN4151 — Half-Bridge LLC Resonant Converter Design</u> <u>Using FSFR-Series Fairchild Power Switch (FPS™)</u>

Part Number	Package	Operating Junction Temperature	R <sub>DS(ON_MAX)</sub>	Maximum Output Power without Heatsink (V <sub>IN</sub> =350~400 V) <sup>(1,2)</sup>	Maximum Output Power with Heatsink (V <sub>IN</sub> =350~400 V) <sup>(1,2)</sup>	
FSFR1800HS	9-SIP					
FSFR1800HSL	9-SIP L-Forming			120 W	260 W	
FSFR1700HS	9-SIP					
FSFR1700HSL	9-SIP L-Forming	-40 to +130°C	1.25 Ω	100 W	200 W	

#### Notes:

1. The junction temperature can limit the maximum output power.

2. Maximum practical continuous power in an open-frame design at 50°C ambient.



## **Pin Configuration** 1 2 3 4 5 6 7 8 9 10 CSSG LV<sub>cc</sub> DL LS CTR RT PG HVcc

Figure 3. Package Diagram

## **Pin Definitions**

Pin #	Name	Description
1	DL	This is the drain of the high-side MOSFET, typically connected to the input DC link voltage.
2	LS	This is the line-sensing pin for the input voltage Under-Voltage Lockout (UVLO).
3	RT	This pin is used for controlling the switching frequency in normal operation. When any protections are triggered, the internal Auto/Restart (A/R) circuit starts to sense the voltage on the pin, which is discharged naturally by external resistance. The IC can be operated with A/R when the voltage decreases 0.1 V. Typically, an opto-coupler is connected to control the switching frequency for the output voltage regulation and resistors for setting minimum / maximum operating frequency.
4	CS	This pin senses the current flowing through the low-side MOSFET. Typically, negative voltage is applied to this pin.
5	SG	This pin is the ground of the control part.
6	PG	This pin is the power ground. This pin is connected to the source of the low-side MOSFET.
7	LV <sub>CC</sub>	This pin is the supply voltage of the control IC.
8	NC	No connection
9	HVcc	This is the supply voltage of the high-side gate-drive circuit.
10	CTR	This is the drain of the low-side MOSFET. Typically, a transformer is connected to this pin.

## **Absolute Maximum Ratings**

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Pa	arameter		Min.	Max.	Unit	
V <sub>DS</sub>	Maximum Drain-to-Source V	oltage (DL-CTR and	d CTR-PG)	500		V	
LV <sub>CC</sub>	Low-Side Supply Voltage			-0.3	25.0	V	
HV <sub>CC</sub> to CTR	High-Side V <sub>CC</sub> Pin to Low-Si	de Drain Voltage		-0.3	25.0	V	
HV <sub>cc</sub>	High-Side Floating Supply V	oltage		-0.3	525.0	V	
V <sub>RT</sub>	Timing Resistor Connecting	and Auto-Restart Pi	n Voltage	-0.3	5.0	V	
V <sub>LS</sub>	Line Sensing Input Voltage			-0.3	LV <sub>CC</sub>	V	
V <sub>CS</sub>	Current Sense (CS) Pin Inpu	ıt Voltage		-5	1	V	
f <sub>sw</sub>	Recommended Switching Fr	requency		10	600	kHz	
dV <sub>CTR</sub> /dt	Allowable Low-Side MOSFE	T Drain Voltage Sle	w Rate		50	V/ns	
D		FSFR1800HS/L	FSFR1800HS/L		11.7	10/	
PD	Total Power Dissipation <sup>(4)</sup> FSFR1700HS/L				11.6	W	
Ŧ	Maximum Junction Tempera	ture <sup>(5)</sup>			+150	°C	
TJ	Recommended Operating Ju	unction Temperature	(5)	-40	+130	ۍ ۲	
T <sub>STG</sub>	Storage Temperature Range	9		-55	+150	°C	
MOSFET Sect	lion						
$V_{\text{DGR}}$	Drain Gate Voltage (R <sub>GS</sub> =1 I	MΩ)		500		V	
$V_{GS}$	Gate Source (GND) Voltage				±30	V	
1	Drain Current Pulsed <sup>(6)</sup>	FSFR1800HS/L			23	•	
I <sub>DM</sub>	Drain Current Puised	FSFR1700HS/L			20	- A	
		FSFR1800HS/L	T <sub>C</sub> =25°C		7.0		
	Continuous Drain Current	FSFR 1000HS/L	T <sub>C</sub> =100°C		4.5		
Ι <sub>D</sub>			T <sub>C</sub> =25°C		6.0	A	
		FSFR1700HS/L	T <sub>C</sub> =100°C		3.9		
Package Sect	ion						
Torque	Recommended Screw Torqu	le		5-	~7	kgf∙cm	

These parameters, although guaranteed, are tested only in EDS (wafer test) process. 3.

Per MOSFET when both MOSFETs are conducting. 4.

5. The maximum value of the recommended operating junction temperature is limited by thermal shutdown.

6. Pulse width is limited by maximum junction temperature.

## **Thermal Impedance**

T<sub>A</sub>=25°C unless otherwise specified.

Symbol	Parameter		Value	Unit
٥	Junction-to-Case Center Thermal Impedance	FSFR1800HS/L	10.7	°C/W
θ <sub>JC</sub>	(Both MOSFETs Conducting)	FSFR1700HS/L	10.8	C/ VV
θ <sub>JA</sub>	Junction-to-Ambient Thermal Impedance	FSFR1800HS/L FSFR1700HS/L	80	°C/W

Symbol	Parar	neter	Conditions	Min.	Тур.	Max.	Unit	
MOSFET S	ection							
	Drain to Course Drackda	we Valtage	I <sub>D</sub> =200 μΑ, Τ <sub>A</sub> =25°C	500			v	
BV <sub>DSS</sub>	Drain-to-Source Breakdo	wn vollage	I <sub>D</sub> =200 μA, T <sub>A</sub> =125°C		540		v	
Р	On-State Resistance	FSFR1800HS/L	V <sub>GS</sub> =10 V, I <sub>D</sub> =3.0 A		0.77	0.95	Ω	
R <sub>DS(ON)</sub>	On-State Resistance	FSFR1700HS/L	V <sub>GS</sub> =10 V, I <sub>D</sub> =2.0 A		1.00	1.25	52	
	Body Diode Reverse	FSFR1800HS/L	V <sub>GS</sub> =0 V, I <sub>DIODE</sub> =7.0 A, dI <sub>DIODE</sub> /dt=100 A/µs		160			
t <sub>rr</sub>	Recovery Time <sup>(7)</sup>	FSFR1700HS/L	V <sub>GS</sub> =0 V, I <sub>DIODE</sub> =6.0 A, dI <sub>DIODE</sub> /dt=100 A/µs		160		ns	
0		FSFR1800HS/L			639		pF	
CISS	Input Capacitance <sup>(7)</sup>	FSFR1700HS/L	V <sub>DS</sub> =25 V, V <sub>GS</sub> =0 V,	512 82.1			pF	
0	$O_{1}$ the state $O_{2}$ and $O_{3}$ is the state $O_{1}^{(7)}$	FSFR1800HS/L	f=1.0 MHz				pF	
Coss	Output Capacitance <sup>(7)</sup>	FSFR1700HS/L			66.5		pF	
Supply See	ction			•				
I <sub>LK</sub>	Offset Supply Leakage C	urrent	HV <sub>CC</sub> =V <sub>CTR</sub> =500 V			50	μA	
I <sub>Q</sub> HV <sub>CC</sub>	Quiescent HVcc Supply	Current	(HV <sub>CC</sub> UV+) - 0.1 V		50	120	μA	
I <sub>Q</sub> LV <sub>CC</sub>	Quiescent LVcc Supply (	Current	(LV <sub>CC</sub> UV+) - 0.1 V		100	200	μA	
I <sub>o</sub> HV <sub>cc</sub> Operating HV <sub>cc</sub> Supply C			f <sub>OSC</sub> =50 KHz		6	9	mA	
	Operating HVcc Supply (		No Switching		100	200	μA	
1.1.1/		Numerat (DMC ) (alua)	f <sub>OSC</sub> =50 KHz		7	11	mA	
I <sub>o</sub> LV <sub>cc</sub>	CC Operating LVcc Supply Current (RMS Value)		No Switching		2	4	mA	
UVLO Sect	tion							
LV <sub>CC</sub> UV+	LV <sub>CC</sub> Supply Under-Voltage Positive Going Threshold (LV <sub>CC,START</sub> )		11.2	12.5	13.8	V		
LV <sub>CC</sub> UV-	LV <sub>CC</sub> Supply Under-Volta	ige Negative Going Thi	reshold (LV <sub>CC,STOP</sub> )	8.9	10.0	11.1	V	
LV <sub>CC</sub> UVH	LV <sub>CC</sub> Supply Under-Volta	ige Hysteresis			2.5		V	
HV <sub>CC</sub> UV+	HV <sub>CC</sub> Supply Under-Volt	age Positive Going Thre	eshold (HV <sub>CC,START</sub> )	8.2	9.2	10.2	V	
HV <sub>cc</sub> UV-	HVcc Supply Under-Voltage Negative Going Threshold (HV <sub>CC,STOP</sub> )			7.8	8.7	9.6	V	
HV <sub>CC</sub> UVH	HV <sub>CC</sub> Supply Under-Volt	age Hysteresis			0.5		V	
Oscillator a	& Feedback Section							
V <sub>RT</sub>	Output Voltage on RT Pi	n		1.5	2.0	2.5	V	
f <sub>osc</sub>	Output Oscillation Freque	ency	R <sub>T</sub> =26 kΩ	47	50	53	kHz	
DC	Output Duty Cycle			48	50	52	%	

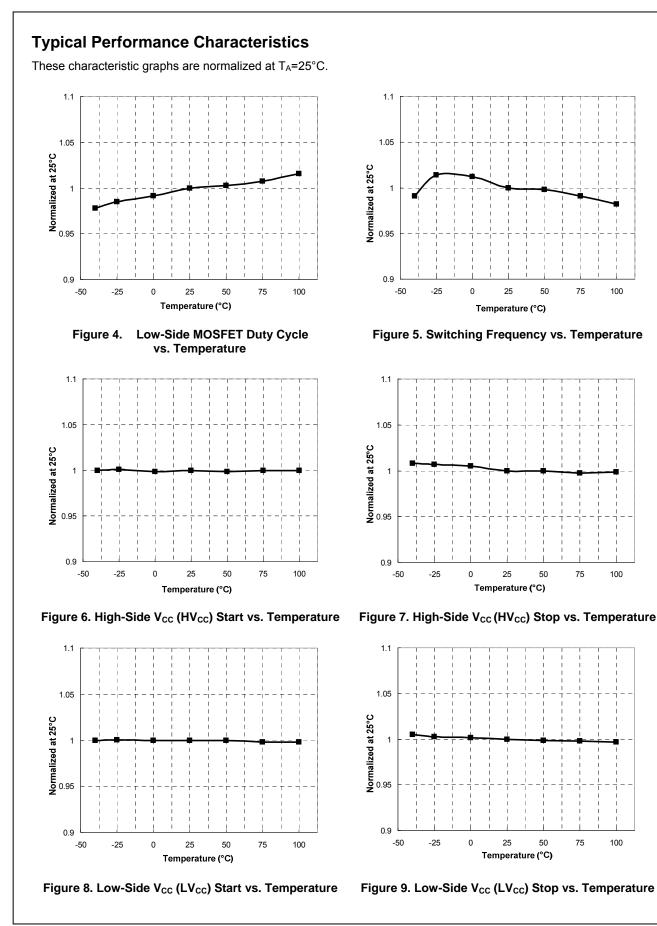
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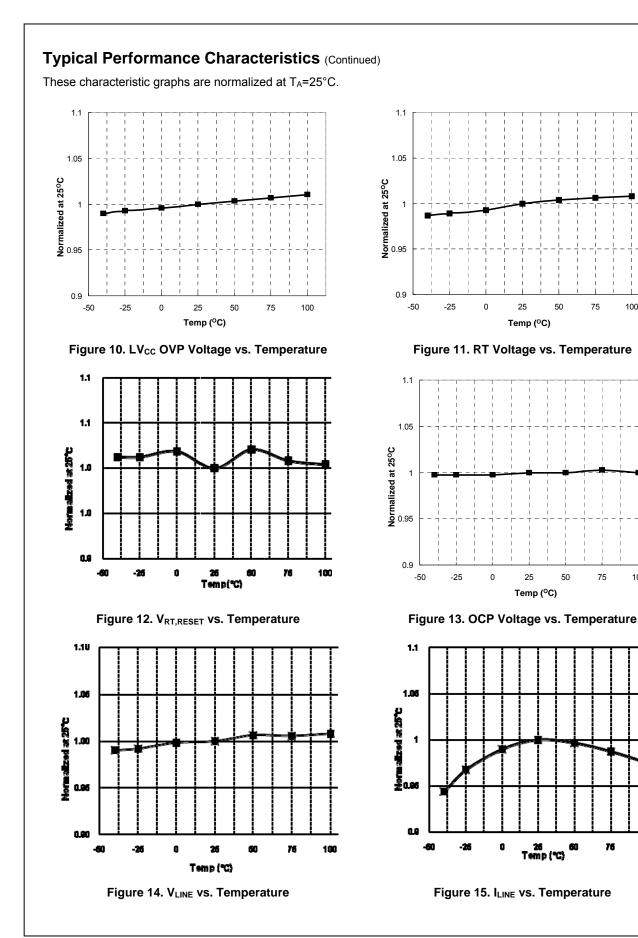
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	Protection	Section					
$V_{\text{LINE}}$ On Threshold of Input Voltage2.382.502.62 $I_{\text{LINE}}$ Hysteresis Current for Line UVLO7.59.511.511.5 $V_{\text{OVP}}$ $LV_{\text{CC}}$ Over-Voltage Protection212325 $V_{\text{AOCP}}$ AOCP Threshold Voltage-1.0-0.9-0.8 $t_{\text{BAO}}$ AOCP Blanking Time <sup>(7)</sup> $V_{\text{CS}} < V_{\text{AOCP}}$ 5011.5 $V_{\text{OCP}}$ OCP Threshold Voltage-0.64-0.58-0.52 $t_{\text{BO}}$ OCP Blanking Time <sup>(7)</sup> $V_{\text{CS}} < V_{\text{OCP}}$ 1.01.52.0 $t_{\text{BO}}$ OCP Blanking Time <sup>(7)</sup> $V_{\text{CS}} < V_{\text{OCP}}$ 1.01.52.010 $t_{\text{BO}}$ Delay Time (Low-Side) Detecting from $V_{\text{AOCP}}$ to Switch Off <sup>(7)</sup> 25040010	V <sub>RT,RESET</sub>	Threshold Voltage to Begin Restart		0.07	0.12	0.17	V
IntelDriverse<	t <sub>DELAY,RESET</sub>	Delay to Disable OSC Circuit After Protection	f <sub>osc</sub> =50 kHz		20		ms
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $	$V_{\text{LINE}}$	On Threshold of Input Voltage	2.38	2.50	2.62	V	
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $	I <sub>LINE</sub>	Hysteresis Current for Line UVLO		7.5	9.5	11.5	μA
t_{BAO}AOCP Blanking Time <sup>(7)</sup> $V_{CS} < V_{AOCP}$ 50 $V_{OCP}$ OCP Threshold Voltage-0.64-0.58-0.52 $t_{BO}$ OCP Blanking Time <sup>(7)</sup> $V_{CS} < V_{OCP}$ 1.01.52.0 $t_{DA}$ Delay Time (Low-Side) Detecting from $V_{AOCP}$ to Switch Off <sup>(7)</sup> 250400m	V <sub>OVP</sub>	LV <sub>CC</sub> Over-Voltage Protection		21	23	25	V
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $	VAOCP	AOCP Threshold Voltage		-1.0	-0.9	-0.8	V
$t_{BO}$ OCP Blanking Time <sup>(7)</sup> $V_{CS} < V_{OCP}$ 1.01.52.0 $\mu$ $t_{DA}$ Delay Time (Low-Side) Detecting from $V_{AOCP}$ to Switch Off <sup>(7)</sup> 250400 $\mu$	t <sub>BAO</sub>	AOCP Blanking Time <sup>(7)</sup>	$V_{CS} < V_{AOCP}$		50		ns
t <sub>DA</sub> Delay Time (Low-Side) Detecting from $V_{AOCP}$ to Switch Off <sup>(7)</sup> 250 400 m	V <sub>OCP</sub>	OCP Threshold Voltage		-0.64	-0.58	-0.52	V
	t <sub>BO</sub>	OCP Blanking Time <sup>(7)</sup>	$V_{CS} < V_{OCP}$	1.0	1.5	2.0	μs
	t <sub>DA</sub>	Delay Time (Low-Side) Detecting from VAOCP to	Switch Off <sup>(7)</sup>		250	400	ns
T <sub>SD</sub> Thermal Shutdown Temperature <sup>(7)</sup> 120 135 150 150	T <sub>SD</sub>	Thermal Shutdown Temperature <sup>(7)</sup>			135	150	°C
	DT	Dead Time <sup>(8)</sup>			350		ns

Notes:

7. 8.

This parameter, although guaranteed, is not tested in production. These parameters, although guaranteed, are tested only in EDS (wafer test) process.



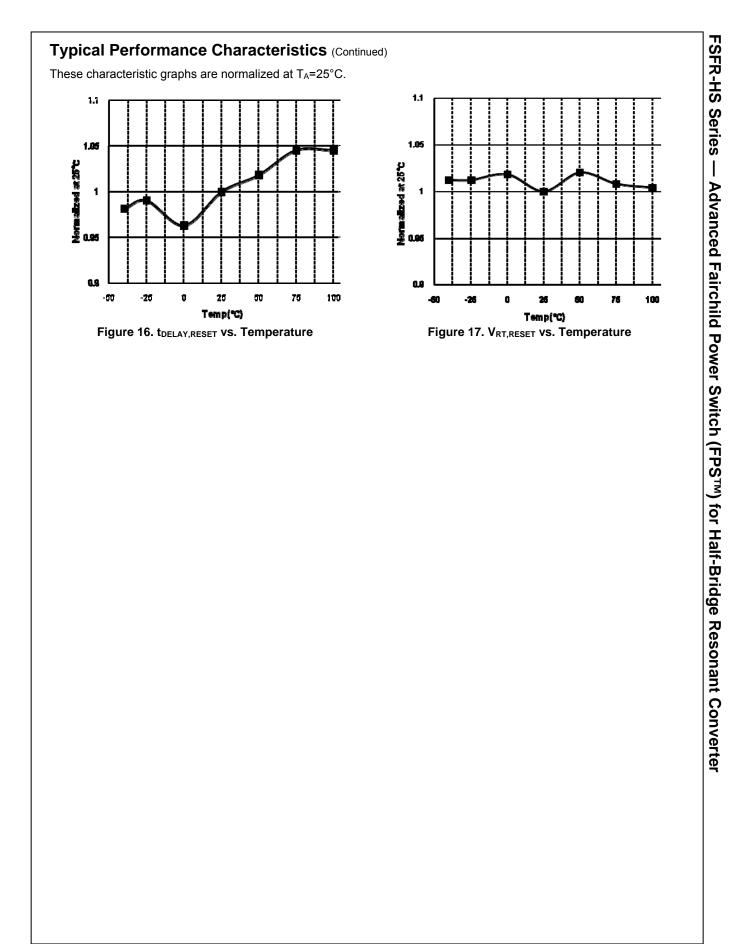


100

100

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76



## **Functional Description**

**1. Basic Operation:** FSFR-HS series is designed to drive high-side and low-side MOSFETs complementarily with 50% duty cycle. A fixed dead time of 350 ns is introduced between consecutive transitions, as shown in Figure 18.

Once LV<sub>CC</sub> is higher than LV<sub>CC,START</sub> = 12.5 V, the IC starts to operate, generates the low-side gate signal, and drives the low-side MOSFET. The bootstrap diode and capacitor is charged by the low-side MOSFET's operation. After the voltage on HV<sub>CC</sub> increases up to HV<sub>CC,START</sub>, typically 9.2 V, the high-side gate signal is generated for the MOSFET.

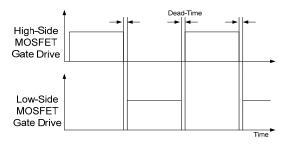
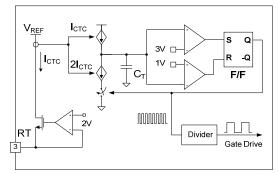


Figure 18. MOSFET Gate Drive Signals

**2.** Internal Oscillator: FSFR-HS series employs a current-controlled oscillator, as shown in Figure 19. Internally, the voltage of the RT pin is regulated at 2 V and the charging / discharging current for the oscillator capacitor,  $C_T$ , is obtained by copying the current flowing out of the RT pin ( $I_{CTC}$ ) using a current mirror. Therefore, the switching frequency increases as  $I_{CTC}$  increases.





**3. Frequency Setting:** Figure 20 shows the typical voltage gain curve of a resonant converter, where the gain is inversely proportional to the switching frequency in the ZVS region. The output voltage can be regulated by modulating the switching frequency. Figure 21 shows the typical circuit configuration for the RT pin, where the opto-coupler transistor is connected to the RT pin to modulate the switching frequency. The switching frequency may be controlled from 20 kHz to 500 kHz.

The minimum switching frequency is determined as:

$$f_{min} = \frac{1}{792 \, p \times R_{min} + 0.54\mu} \, [Hz] \tag{1}$$

Assuming the saturation voltage of opto-coupler transistor is 0.2 V, the maximum switching frequency is determined as:

$$f_{max} = \frac{1}{792 \, p \times R_{min} \, || \, R_{max} + 0.54 \, \mu} \, [Hz] \tag{2}$$

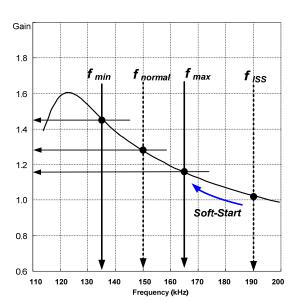


Figure 20. Resonant Converter Typical Gain Curve

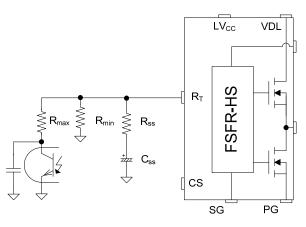


Figure 21. Frequency Control Circuit

To prevent excessive inrush current and overshoot of output voltage during startup, the IC needs to increase the voltage gain of the resonant converter progressively. Since the voltage gain of the resonant converter is inversely proportional to the switching frequency, softstart is implemented by sweeping down the switching frequency from an initial high frequency ( $f_{ISS}$ ) until the output voltage is established.

The soft-start circuit is constructed by connecting R-C series network to the RT pin, as shown in Figure 21. Initially, the operating frequency is set by the parallel impedance of  $R_{SS}$  and  $R_{min}$ .

The initial maximum frequency can be set up to 600 kHz, which is given by:

$$f_{ss} = \frac{1}{792 \, p \times R_{\min} \parallel R_{ss} + 0.54 \mu} \, [Hz] \tag{3}$$

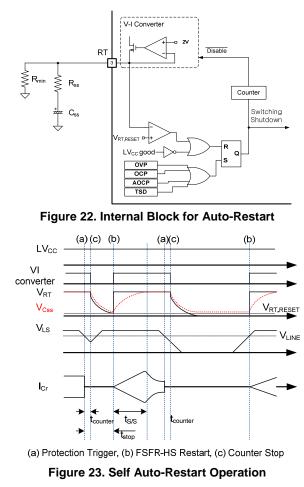
The soft-start time,  $t_{SS}$ , can be calculated by:

$$t_{SS} = \mathcal{I} \times R_{SS} \cdot C_{SS} \quad [s] \tag{4}$$

**4. Self Auto-Restart:** The FSFR-HS series can restart automatically even though any built-in protections are triggered in case external supply voltage is applied. As shown in Figure 22 and Figure 23; once a protection is triggered, the power MOSFET immediately stops. The counter starts to operate and 1008-clocks are counted, then the V-I converter is disabled. C<sub>SS</sub> starts to be naturally discharged with the series impedance of R<sub>SS</sub> and R<sub>min</sub> until V<sub>RT</sub> drops to V<sub>RT,RESET</sub>, typically 0.1 V. Then, all protections are reset and the V-I converter resumes. The FSFR-HS starts switching again with soft-start.

The counter operating time for 1008-clocks after protection activation is set by the current out of the RT pin until  $V_{RT}$  drops to  $V_{RT,RESET}$ . Finally, the stop time of FSFR-HS can be estimated, without considering the counter operation time, as:

$$t_{STOP} = \mathcal{Z}C_{SS} \cdot (R_{SS} + R_{min}) [s]$$
(5)



**5. Protection Circuits:** The FSFR-HS series has several self-protective functions; such as Over-Current Protection (OCP), Abnormal Over-Current Protection (AOCP), Over-Voltage Protection (OVP), Thermal Shutdown (TSD), and Line Under-Voltage Lockout (LUVLO or Brownout). These protections are Auto-Restart Mode protections, as shown in Figure 24.

Once a fault condition is detected, switching is instantly terminated and the MOSFETs remain off. When LV<sub>CC</sub> falls to the LV<sub>CC</sub> stop voltage of 10 V and V<sub>RT</sub> is lower than V<sub>RT,RESET</sub> of 0.1 V, the protection is reset. The FSFR-HS resumes normal operation when LV<sub>CC</sub> reaches the start voltage of 12.5 V.

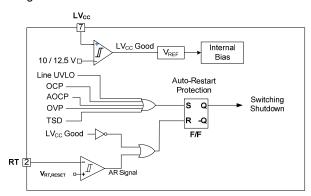


Figure 24. Protection Blocks

**5.1 Over-Current Protection (OCP)**: When the sensing pin voltage drops below -0.58 V and its duration becomes more than OCP blanking time of 1.5 µs, OCP is triggered and the MOSFETs remain off.

**5.2 Abnormal Over-Current Protection (AOCP)**: If the secondary rectifier diodes are shorted, large current with extremely high di/dt can flow through the MOSFET before OCP is triggered. AOCP is triggered without shutdown delay if the sensing pin voltage drops below -0.9 V.

**5.3 Over-Voltage Protection (OVP)**: When the LV<sub>CC</sub> reaches 23 V, OVP is triggered. This protection is used when auxiliary winding of the transformer supplies  $V_{CC}$  to the FPS<sup>TM</sup>.

**5.4 Thermal Shutdown (TSD)**: The MOSFETs and the control IC in one package make it easier for the control IC to detect the abnormal over-temperature of the MOSFETs. If the temperature exceeds approximately 130°C, thermal shutdown triggers.

6. Line Under-Voltage Lockout (UVLO): FSFR-HS includes precise line UVLO (or brownout) with programmable hysteresis voltage. This function can start or restart the IC when  $V_{LS}$  for the scale-down voltage of the DC-link by the sensing resistors, R1 and R2, is higher than  $V_{LINE}$  of 2.5 V as the DC-link voltage increases and vice versa. A hysteresis voltage between the start and stop voltage of the IC is programmable by  $I_{LINE}$ . In normal operation, the comparator's output is HIGH and  $I_{LINE}$  is deactivated so that a voltage on LS pin,  $V_{LS}$ , can be obtained as a divided voltage by R1 and R2. On the contrary,  $I_{LINE}$  is generated by the difference between the current through R1 and  $I_{LINE}$ .

 $C_{\text{Filter}}$  can be used to reduce some noise induced from transformer or switching transition. Generally, hundreds of pico-farad to tens of nano-farad is adequate, depending on the quantity of noise.

The start and stop input-voltage can be calculated as:

$$V_{dc-link,STOP} = V_{LINE} \times \frac{R1 + R2}{R2} \quad [V]$$
(6)

$$V_{dc-link,START} = V_{dc-link,STOP} + I_{LINE} \times R1 \ [V]$$
(7)

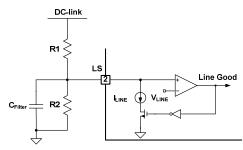


Figure 25. Half-Wave Sensing

**7. Simple Remote-On/Off:** The power stage can be shutdown with optional Auto-Restart Mode, as shown in Figure 26.

To configure an external protection with Auto-Restart Mode, an opto-coupler and the LS pin are used. When the voltage on the LS pin is pulled below  $V_{\text{LINE}}$  (2.5 V), the IC stops during the status holds. However, the opto-coupler stops pulling down and the IC can perform the auto-restart operation itself.

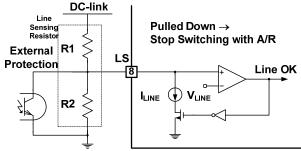


Figure 26. External Protection Circuits

8. Current-Sensing Methods: FSFR-HS series employs negative voltage sensing to detect the drain current of MOSFET, which allows a low-noise resistive sensing using a filter with low time-constant and capacitive sensing method.

**8.1 Resistive Sensing Method:** The IC can sense drain current as a negative voltage, as shown in Figure 27 and Figure 28. Half-wave sensing allows low power dissipation in the sensing resistor; while full-wave sensing has less switching noise in the sensing signal. For a time constant range for the filter, 3/100~1/10 of the operating frequency is reasonable.

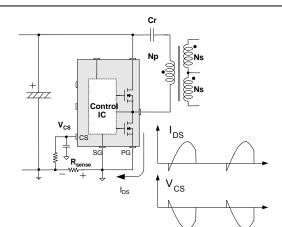
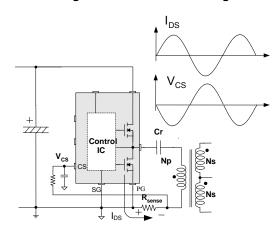


Figure 27. Half-Wave Sensing

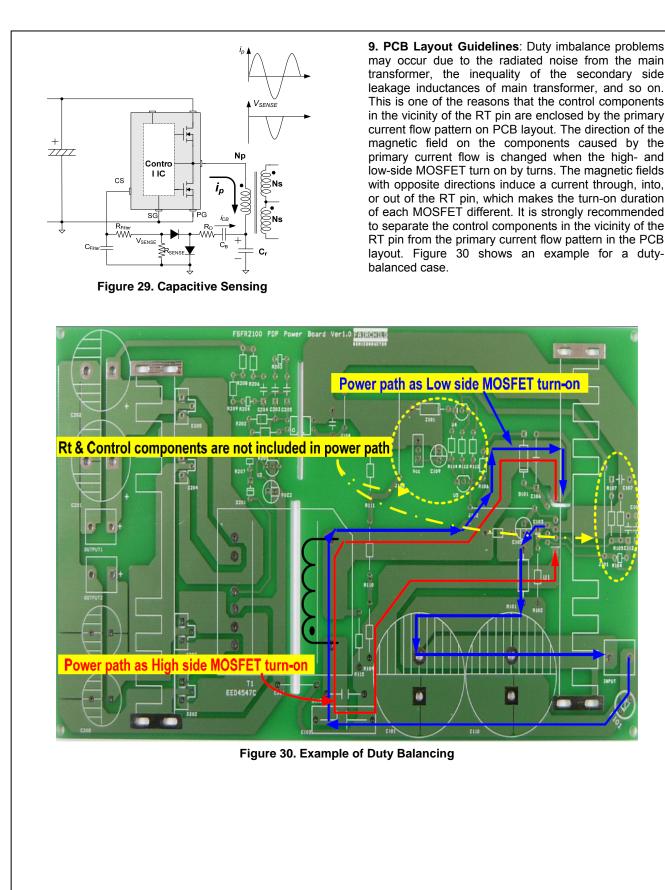


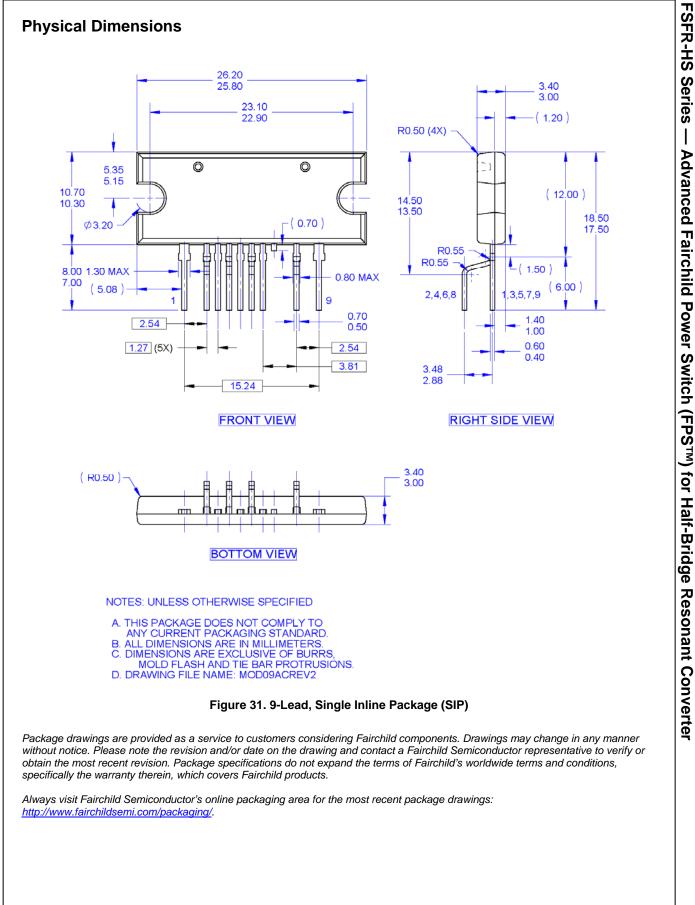
#### Figure 28. Full-Wave Sensing

**8.2 Capacitive Sensing Method:** The drain current can be sensed using an additional capacitor parallel with the resonant capacitor, as shown in Figure 29. During the low-side switch turn on, the current,  $i_{CB}$  through  $C_B$ , makes  $V_{SENSE}$  across  $R_{SENSE}$ . The  $i_{CB}$  is scale-down of  $i_p$  by the impedance ratio of  $C_r$  and  $C_B$ . Generally, 1/100~1/1000 is adequate for the ratio of  $C_B$  against  $C_r$ .  $R_D$  is used as a damper for reducing noise generated by switching transition. Several hundreds of ohm to a few of kilo-ohms can be normally used.

V<sub>SENSE</sub> can be estimated as;

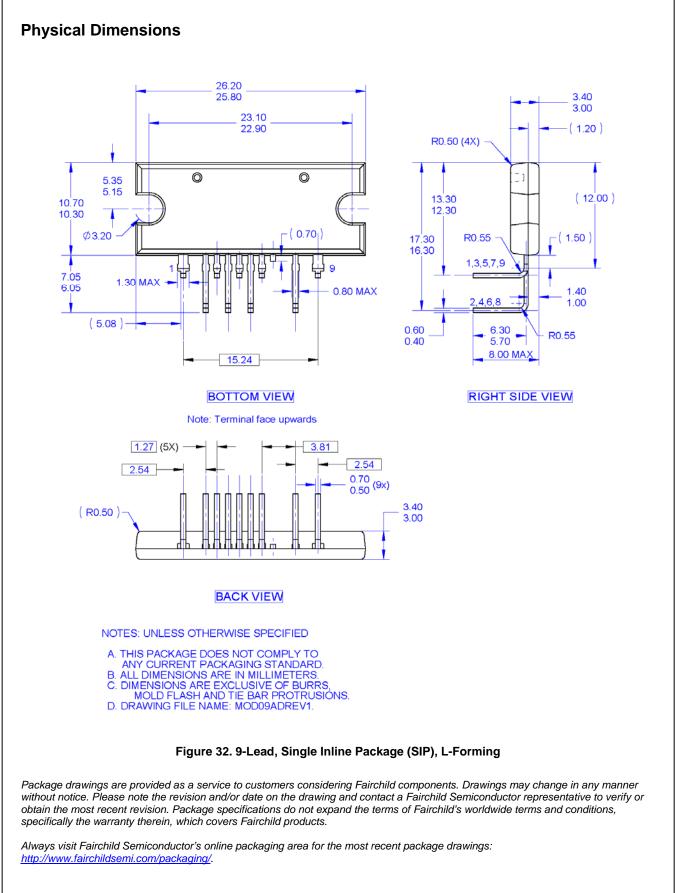
$$V_{sense} = I_{Cr}^{\ pk} \frac{C_B}{Cr} \cdot R_{sense} [V]$$
(8)





**FSFR-HS Series** 

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